



GENERAL DESCRIPTION

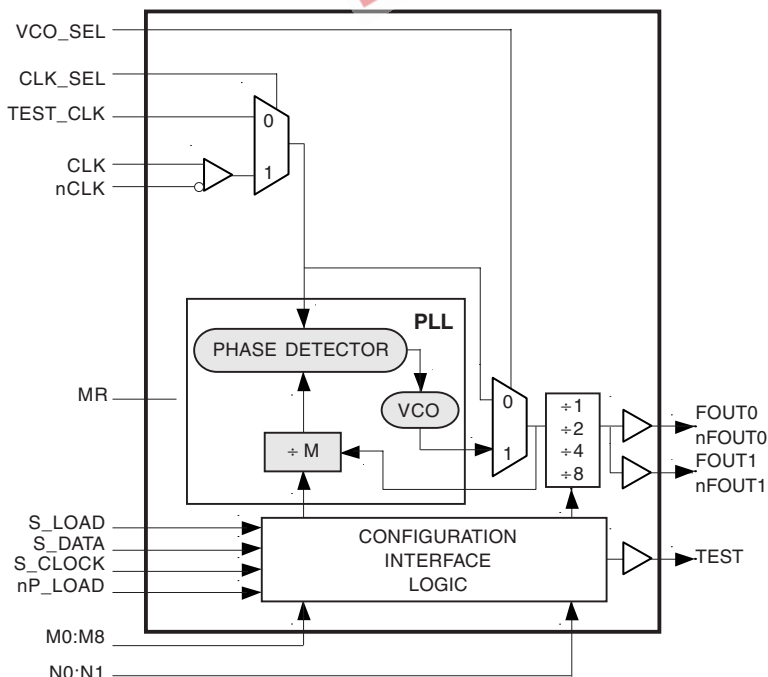


The ICS8432I-101 is a general purpose, dual output Differential-to-3.3V LVPECL high frequency synthesizer and a member of the HiPerClockS™ family of High Performance Clock Solutions from ICS. The ICS8432I-101 has a selectable TEST_CLK or CLK, nCLK inputs. The TEST_CLK input accepts LVCMOS or LVTTTL input levels and translates them to 3.3V LVPECL levels. The CLK, nCLK pair can accept most standard differential input levels. The VCO operates at a frequency range of 250MHz to 700MHz. The VCO frequency is programmed in steps equal to the value of the input differential or single ended reference frequency. The VCO and output frequency can be programmed using the serial or parallel interfaces to the configuration logic. The low phase noise characteristics of the ICS8432I-101 makes it an ideal clock source for Gigabit Ethernet and SONET applications.

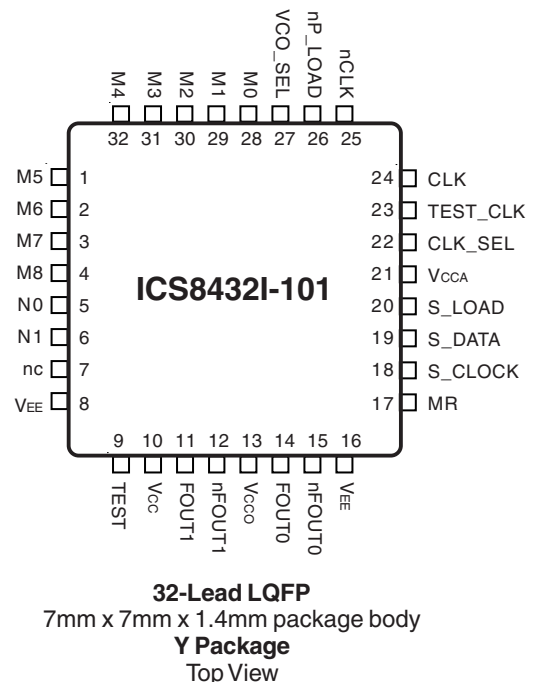
FEATURES

- Dual differential 3.3V LVPECL outputs
- Selectable CLK, nCLK or LVCMOS/LVTTTL TEST_CLK
- TEST_CLK can accept the following input levels: LVCMOS or LVTTTL
- CLK, nCLK pair can accept the following differential input levels: LVPECL, LVDS, LVHSTL, SSTL, HCSL
- CLK, nCLK or TEST_CLK maximum input frequency: 40MHz
- Output frequency range: 25MHz to 700MHz
- VCO range: 250MHz to 700MHz
- Accepts any single-ended input signal on CLK input with resistor bias on nCLK input
- Parallel interface for programming counter and output dividers
- RMS period jitter: 5ps (maximum)
- Cycle-to-cycle jitter: 25ps (maximum)
- 3.3V supply voltage
- -40°C to 85°C ambient operating temperature
- Lead-Free package fully RoHS compliant

BLOCK DIAGRAM



PIN ASSIGNMENT





FUNCTIONAL DESCRIPTION

NOTE: The functional description that follows describes operation using a 25MHz clock input. Valid PLL loop divider values for different input frequencies are defined in the Input Frequency Characteristics, Table 5, NOTE 1.

The ICS8432I-101 features a fully integrated PLL and therefore requires no external components for setting the loop bandwidth. A differential clock input is used as the input to the ICS8432-101. This input is fed into the phase detector. A 25MHz clock input provides a 25MHz phase detector reference frequency. The VCO of the PLL operates over a range of 250MHz to 700MHz. The output of the M divider is also applied to the phase detector.

The phase detector and the M divider force the VCO output frequency to be M times the reference frequency by adjusting the VCO control voltage. Note, that for some values of M (either too high or too low), the PLL will not achieve lock. The output of the VCO is scaled by a divider prior to being sent to each of the LVPECL output buffers. The divider provides a 50% output duty cycle.

The programmable features of the ICS8432I-101 support two input modes to program the PLL M divider and N output divider. The two input operational modes are parallel and serial. Figure 1 shows the timing diagram for each mode. In parallel mode, the nP_LOAD input is initially LOW. The data on inputs M0 through M8 and N0 and N1 is passed directly to the M divider and N output divider. On the LOW-to-HIGH transition of the nP_LOAD input, the data is latched and the M divider remains loaded until the next LOW transition on nP_LOAD or until a se-

rial event occurs. As a result, the M and N bits can be hardwired to set the M divider and N output divider to a specific default state that will automatically occur during power-up. The TEST output is LOW when operating in the parallel input mode. The relationship between the VCO frequency, the input frequency and the M divider is defined as follows: $f_{VCO} = f_{IN} \times M$

The M value and the required values of M0 through M8 are shown in Table 3B, Programmable VCO Frequency Function Table. Valid M values for which the PLL will achieve lock for a 25MHz reference are defined as $8 \leq M \leq 28$. The frequency out is defined as follows: $f_{OUT} = \frac{f_{VCO}}{N} = f_{IN} \times \frac{M}{N}$

Serial operation occurs when nP_LOAD is HIGH and S_LOAD is LOW. The shift register is loaded by sampling the S_DATA bits with the rising edge of S_CLOCK. The contents of the shift register are loaded into the M divider and N output divider when S_LOAD transitions from LOW-to-HIGH. The M divide and N output divide values are latched on the HIGH-to-LOW transition of S_LOAD. If S_LOAD is held HIGH, data at the S_DATA input is passed directly to the M divider and N output divider on each rising edge of S_CLOCK. The serial mode can be used to program the M and N bits and test bits T1 and T0. The internal registers T0 and T1 determine the state of the TEST output as follows:

| T1 | T0 | TEST Output |
|----|----|------------------------------|
| 0 | 0 | LOW |
| 0 | 1 | S_Data, Shift Register Input |
| 1 | 0 | Output of M divider |
| 1 | 1 | CMOS Fout |

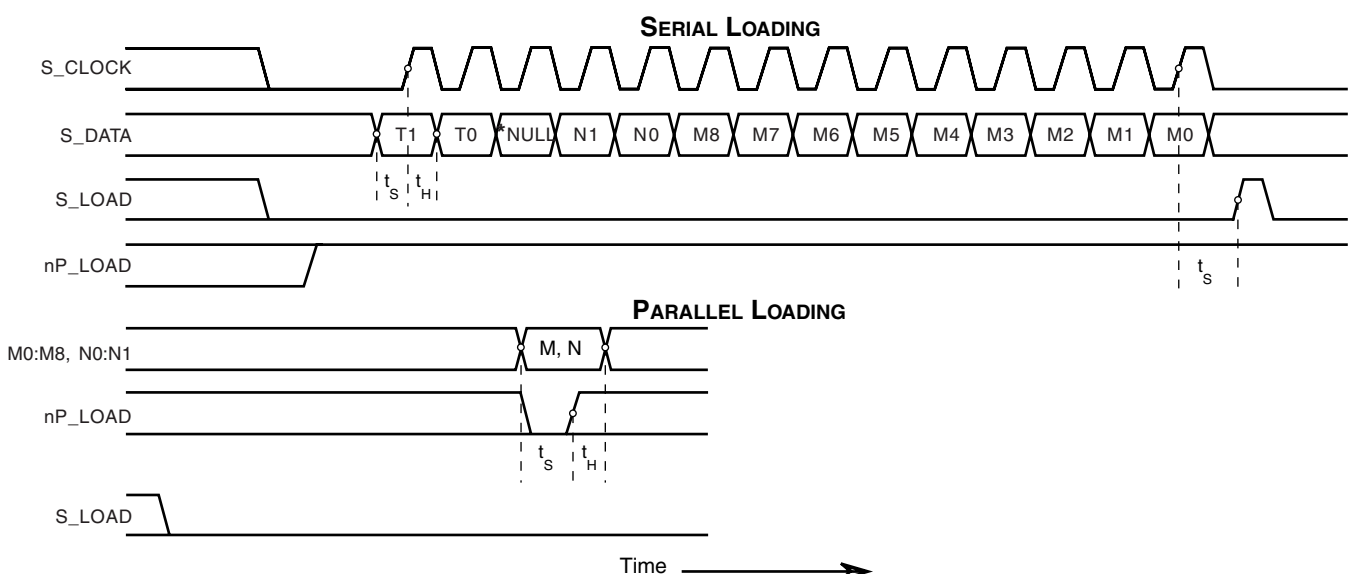


FIGURE 1. PARALLEL & SERIAL LOAD OPERATIONS

*NOTE: The NULL timing slot must be observed.



TABLE 1. PIN DESCRIPTIONS

| Number | Name | Type | | Description |
|---------------------------------|--------------------------------------|--------|----------|---|
| 1 | M5 | Input | Pullup | M divider inputs. Data latched on LOW-to-HIGH transition of nP_LOAD input. LVCMOS / LVTTTL interface levels. |
| 2, 3, 4 28, 29 30, 31, 32 | M6, M7, M8, M0, M1, M2, M3, M4 | Input | Pulldown | |
| 5, 6 | N0, N1 | Input | Pulldown | Determines output divider value as defined in Table 3C, Function Table. LVCMOS / LVTTTL interface levels. |
| 7 | nc | Unused | | No connect. |
| 8, 16 | V _{EE} | Power | | Negative supply pins. |
| 9 | TEST | Output | | Test output which is ACTIVE in the serial mode of operation. Output driven LOW in parallel mode. LVCMOS / LVTTTL interface levels. |
| 10 | V _{CC} | Power | | Core supply pin. |
| 11, 12 | FOUT1, nFOUT1 | Output | | Differential output for the synthesizer. 3.3V LVPECL interface levels. |
| 13 | V _{CCO} | Power | | Output supply pin. |
| 14, 15 | FOUT0, nFOUT0 | Output | | Differential output for the synthesizer. 3.3V LVPECL interface levels. |
| 17 | MR | Input | Pulldown | Active High Master Reset. When logic HIGH, the internal dividers are reset causing the true outputs FOUTx to go low and the inverted outputs nFOUTx to go high. When logic LOW, the internal dividers and the outputs are enabled. Assertion of MR does not affect loaded M, N, and T values. LVCMOS / LVTTTL interface levels. |
| 18 | S_CLOCK | Input | Pulldown | Clocks in serial data present at S_DATA input into the shift register on the rising edge of S_CLOCK. LVCMOS / LVTTTL interface levels. |
| 19 | S_DATA | Input | Pulldown | Shift register serial input. Data sampled on the rising edge of S_CLOCK. LVCMOS / LVTTTL interface levels. |
| 20 | S_LOAD | Input | Pulldown | Controls transition of data from shift register into the dividers. LVCMOS / LVTTTL interface levels. |
| 21 | V _{CCA} | Power | | Analog supply pin. |
| 22 | CLK_SEL | Input | Pullup | Clock select input. Selects between differential clock input or TEST_CLK input as the PLL reference source. When HIGH, selects CLK, nCLK inputs. When LOW, selects TEST_CLK input. LVCMOS / LVTTTL interface levels. |
| 23 | TEST_CLK | Input | Pulldown | Test clock input. LVCMOS / LVTTTL interface levels. |
| 24 | CLK | Input | Pulldown | Non-inverting differential clock input. |
| 25 | nCLK | Input | Pullup | Inverting differential clock input. |
| 26 | nP_LOAD | Input | Pulldown | Parallel load input. Determines when data present at M8:M0 is loaded into M divider, and when data present at N1:N0 sets the N output divider value. LVCMOS / LVTTTL interface levels. |
| 27 | VCO_SEL | Input | Pullup | Determines whether synthesizer is in PLL or bypass mode. LVCMOS / LVTTTL interface levels. |

NOTE: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

TABLE 2. PIN CHARACTERISTICS

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------------------|-------------------------|-----------------|---------|---------|---------|-------|
| C _{IN} | Input Capacitance | | | 4 | | pF |
| R _{PULLUP} | Input Pullup Resistor | | | 51 | | kΩ |
| R _{PULLDOWN} | Input Pulldown Resistor | | | 51 | | kΩ |



TABLE 3A. PARALLEL AND SERIAL MODE FUNCTION TABLE

| Inputs | | | | | | | Conditions |
|--------|---------|------|------|--------|---------|--------|---|
| MR | nP_LOAD | M | N | S_LOAD | S_CLOCK | S_DATA | |
| H | X | X | X | X | X | X | Reset. Forces outputs LOW. |
| L | L | Data | Data | X | X | X | Data on M and N inputs passed directly to the M divider and N output divider. TEST output forced LOW. |
| L | ↑ | Data | Data | L | X | X | Data is latched into input registers and remains loaded until next LOW transition or until a serial event occurs. |
| L | H | X | X | L | ↑ | Data | Serial input mode. Shift register is loaded with data on S_DATA on each rising edge of S_CLOCK. |
| L | H | X | X | ↑ | L | Data | Contents of the shift register are passed to the M divider and N output divider. |
| L | H | X | X | ↓ | L | Data | M divider and N output divider values are latched. |
| L | H | X | X | L | X | X | Parallel or serial inputs do not affect shift registers. |
| L | H | X | X | H | ↑ | Data | S_DATA passed directly to M divider as it is clocked. |

NOTE: L = LOW
H = HIGH
X = Don't care
↑ = Rising edge transition
↓ = Falling edge transition

TABLE 3B. PROGRAMMABLE VCO FREQUENCY FUNCTION TABLE

| VCO Frequency (MHz) | M Divide | 256 | 128 | 64 | 32 | 16 | 8 | 4 | 2 | 1 |
|---------------------|----------|-----|-----|----|----|----|----|----|----|----|
| | | M8 | M7 | M6 | M5 | M4 | M3 | M2 | M1 | M0 |
| 250 | 10 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 |
| 275 | 11 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 1 |
| • | • | • | • | • | • | • | • | • | • | • |
| • | • | • | • | • | • | • | • | • | • | • |
| 650 | 26 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0 |
| 675 | 27 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 |
| 700 | 28 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 0 |

NOTE 1: These M divide values and the resulting frequencies correspond to differential input or TEST_CLK input frequency of 25MHz.

TABLE 3C. PROGRAMMABLE OUTPUT DIVIDER FUNCTION TABLE

| Inputs | | N Divider Value | Output Frequency (MHz) | |
|--------|----|-----------------|------------------------|---------|
| N1 | N0 | | Minimum | Maximum |
| 0 | 0 | 1 | 250 | 700 |
| 0 | 1 | 2 | 125 | 350 |
| 1 | 0 | 4 | 62.5 | 175 |
| 1 | 1 | 8 | 31.25 | 87.5 |



ABSOLUTE MAXIMUM RATINGS

| | |
|--|--------------------------|
| Supply Voltage, V_{CC} | 4.6V |
| Inputs, V_I | -0.5V to $V_{CC} + 0.5V$ |
| Outputs, I_O | |
| Continuous Current | 50mA |
| Surge Current | 100mA |
| Package Thermal Impedance, θ_{JA} | 47.9°C/W (0 lfpm) |
| Storage Temperature, T_{STG} | -65°C to 150°C |

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

TABLE 4A. POWER SUPPLY DC CHARACTERISTICS, $V_{CC} = V_{CCA} = V_{CCO} = 3.3V \pm 5\%$, $T_A = -40^\circ C$ TO $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------|-----------------------|-----------------|---------|---------|---------|-------|
| V_{CC} | Core Supply Voltage | | 3.135 | 3.3 | 3.465 | V |
| V_{CCA} | Analog Supply Voltage | | 3.135 | 3.3 | 3.465 | V |
| V_{CCO} | Output Supply Voltage | | 3.135 | 3.3 | 3.465 | V |
| I_{EE} | Power Supply Current | | | | 120 | mA |
| I_{CCA} | Analog Supply Current | | | | 15 | mA |

TABLE 4B. LVCMOS / LVTTTL DC CHARACTERISTICS, $V_{CC} = V_{CCA} = V_{CCO} = 3.3V \pm 5\%$, $T_A = -40^\circ C$ TO $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|----------|---------------------|--|--|---------|----------------|---------|
| V_{IH} | Input High Voltage | VCO_SEL, CLK_SEL, MR, S_LOAD, S_DATA, S_CLOCK, nP_LOAD, M0:M8, N0:N1 | 2 | | $V_{CC} + 0.3$ | V |
| | | TEST_CLK | 2 | | $V_{CC} + 0.3$ | V |
| V_{IL} | Input Low Voltage | VCO_SEL, CLK_SEL, MR, S_LOAD, S_DATA, S_CLOCK, nP_LOAD, M0:M8, N0:N1 | -0.3 | | 0.8 | V |
| | | TEST_CLK | -0.3 | | 1.3 | V |
| I_{IH} | Input High Current | M0-M4, M6-M8, N0, N1, MR, S_CLOCK, TEST_CLK, S_DATA, S_LOAD, nP_LOAD | $V_{CC} = V_{IN} = 3.465V$ | | 150 | μA |
| | | M5, CLK_SEL, VCO_SEL | $V_{CC} = V_{IN} = 3.465V$ | | 5 | μA |
| I_{IL} | Input Low Current | M0-M4, M6-M8, N0, N1, MR, S_CLOCK, TEST_CLK, S_DATA, S_LOAD, nP_LOAD | $V_{CC} = 3.465V,$ $V_{IN} = 0V$ | -5 | | μA |
| | | M5, CLK_SEL, VCO_SEL | $V_{CC} = 3.465V,$ $V_{IN} = 0V$ | -150 | | μA |
| V_{OH} | Output High Voltage | TEST | $V_{CC} = 3.135V,$ $I_{OH} = -36mA$ | 2.6 | | V |
| V_{OL} | Output Low Voltage | TEST | $V_{CC} = 3.135V,$ $I_{OL} = 36mA$ | | 0.5 | V |



Integrated
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ICS8432I-101
700MHz,

DIFFERENTIAL-TO-3.3V LVPECL FREQUENCY SYNTHESIZER

TABLE 4C. DIFFERENTIAL DC CHARACTERISTICS, $V_{CC} = V_{CCA} = V_{CCO} = 3.3V \pm 5\%$, $T_A = -40^\circ C$ TO $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------|----------------------------|-----------------|--------------------------------|---------|-----------------|---------|
| I_{IH} | Input High Current | CLK | $V_{CC} = V_{IN} = 3.465V$ | | 150 | μA |
| | | nCLK | $V_{CC} = V_{IN} = 3.465V$ | | 5 | μA |
| I_{IL} | Input Low Current | CLK | $V_{CC} = 3.465V, V_{IN} = 0V$ | -5 | | μA |
| | | nCLK | $V_{CC} = 3.465V, V_{IN} = 0V$ | -150 | | μA |
| V_{PP} | Peak-to-Peak Input Voltage | | 0.15 | | 1.3 | V |
| V_{CMR} | Common Mode Input Voltage | | $V_{EE} + 0.5$ | | $V_{CC} - 0.85$ | V |

NOTE 1: For single ended applications, the maximum input voltage for CLK, nCLK is $V_{CC} + 0.3V$.

NOTE 2: Common mode voltage is defined as V_{IH} .

TABLE 4D. LVPECL DC CHARACTERISTICS, $V_{CC} = V_{CCA} = V_{CCO} = 3.3V \pm 5\%$, $T_A = -40^\circ C$ TO $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-------------|-----------------------------------|-----------------|-----------------|---------|-----------------|-------|
| V_{OH} | Output High Voltage; NOTE 1 | | $V_{CCO} - 1.4$ | | $V_{CCO} - 0.9$ | V |
| V_{OL} | Output Low Voltage; NOTE 1 | | $V_{CCO} - 2.0$ | | $V_{CCO} - 1.7$ | V |
| V_{SWING} | Peak-to-Peak Output Voltage Swing | | 0.6 | | 1.0 | V |

NOTE 1: Outputs terminated with 50Ω to $V_{CCO} - 2V$.

TABLE 5. INPUT FREQUENCY CHARACTERISTICS, $V_{CC} = V_{CCA} = V_{CCO} = 3.3V \pm 5\%$, $T_A = -40^\circ C$ TO $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|----------|-----------------|-------------------|---------|---------|---------|-------|
| f_{IN} | Input Frequency | TEST_CLK; NOTE 1 | 14 | | 25 | MHz |
| | | CLK, nCLK; NOTE 1 | 14 | | 25 | MHz |
| | | S_CLOCK | | | 25 | MHz |

NOTE 1: For the differential input and TEST_CLK frequency range, the M value must be set for the VCO to operate within the 250MHz to 700MHz range. Using the minimum input frequency of 14MHz, valid values of M are $18 \leq M \leq 50$. Using the maximum frequency of 25MHz, valid values of M are $10 \leq M \leq 28$.

TABLE 6. AC CHARACTERISTICS, $V_{CC} = V_{CCA} = V_{CCO} = 3.3V \pm 5\%$, $T_A = -40^\circ C$ TO $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|----------------|----------------------------------|--------------------|----------------------|---------|----------------------|-------|
| F_{OUT} | Output Frequency | | 31.25 | | 700 | MHz |
| $f_{jit(cc)}$ | Cycle-to-Cycle Jitter; NOTE 1, 3 | $f_{VCO} > 350MHz$ | | | 25 | ps |
| $f_{jit(per)}$ | Period Jitter, RMS; NOTE 1 | $f_{OUT} > 100MHz$ | | | 5 | ps |
| $t_{sk(o)}$ | Output Skew; NOTE 2, 3 | | | | 15 | ps |
| t_R / t_F | Output Rise/Fall Time | 20% to 80% | 200 | | 700 | ps |
| t_s | Setup Time | M, N to nP_LOAD | 5 | | | ns |
| | | S_DATA to S_CLOCK | 5 | | | ns |
| | | S_CLOCK to S_LOAD | 5 | | | ns |
| t_H | Hold Time | M, N to nP_LOAD | 5 | | | ns |
| | | S_DATA to S_CLOCK | 5 | | | ns |
| | | S_CLOCK to S_LOAD | 5 | | | ns |
| odc | Output Duty Cycle | $N > 1$ | 47 | | 53 | % |
| t_{PW} | Output Pulse Width | $N = 1$ | $t_{PERIOD}/2 - 150$ | | $t_{PERIOD}/2 + 150$ | ps |
| t_{LOCK} | PLL Lock Time | | | | 1 | ms |

See Parameter Measurement Information section.

NOTE 1: Jitter performance using XTAL inputs.

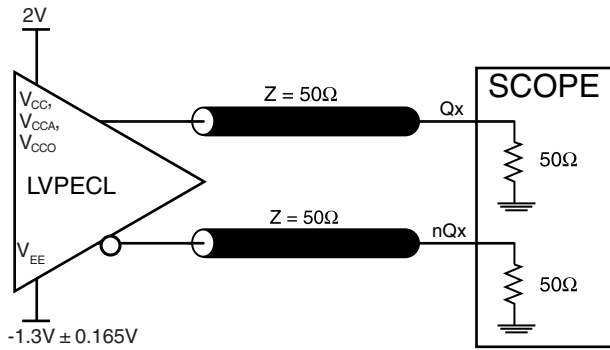
NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at the output differential cross points.

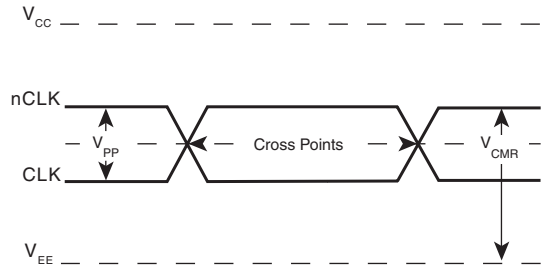
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.



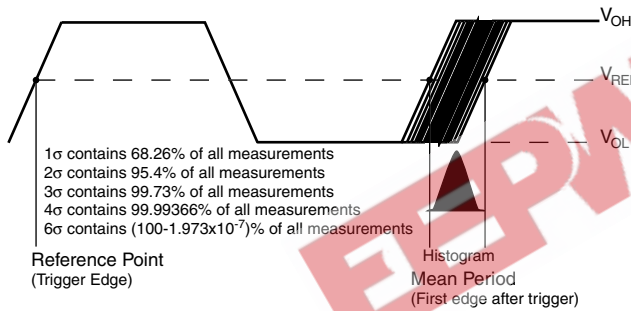
PARAMETER MEASUREMENT INFORMATION



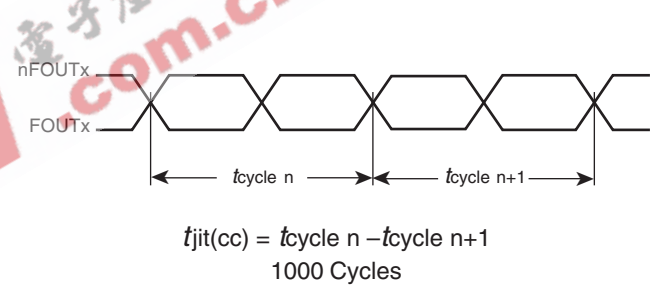
3.3V OUTPUT LOAD AC TEST CIRCUIT



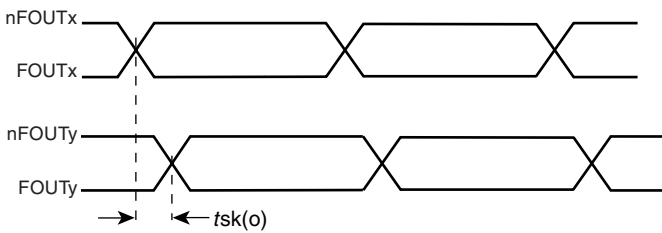
DIFFERENTIAL INPUT LEVEL



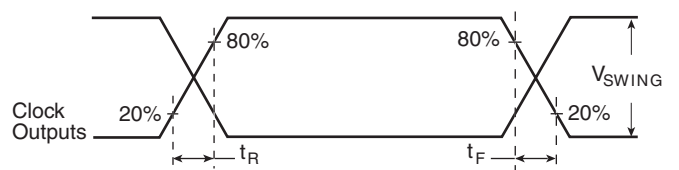
PERIOD JITTER



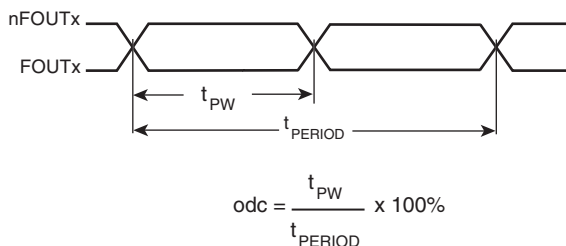
CYCLE-TO-CYCLE JITTER



OUTPUT SKEW



OUTPUT RISE/FALL TIME



OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD



APPLICATION INFORMATION

STORAGE AREA NETWORKS

A variety of technologies are used for interconnection of the elements within a SAN. The tables below list the common application frequencies as well as the ICS8432I-101 configurations used to generate the appropriate frequency.

Table 7. Common SANs Application Frequencies

| Interconnect Technology | Clock Rate | Reference Frequency to SERDES (MHz) | Crystal Frequency (MHz) |
|-------------------------|----------------------------------|-------------------------------------|-------------------------|
| Gigabit Ethernet | 1.25 GHz | 125, 250, 156.25 | 25, 19.53125 |
| Fibre Channel | FC1 1.0625 GHz FC2 2.1250 GHz | 106.25, 53.125, 132.8125 | 16.6015625, 25 |
| Infiniband | 2.5 GHz | 125, 250 | 25 |

Table 8. Configuration Details for SANs Applications

| Interconnect Technology | CLK, nCLK Input (MHz) | ICS8432I-101 Output Frequency to SERDES (MHz) | ICS8432I-101 M & N Settings | | | | | | | | | | |
|-------------------------|-----------------------|---|-----------------------------|----|----|----|----|----|----|----|----|----|----|
| | | | M8 | M7 | M6 | M5 | M4 | M3 | M2 | M1 | M0 | N1 | N0 |
| Gigabit Ethernet | 25 | 125 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 0 |
| | 25 | 250 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 1 |
| | 25 | 156.25 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 0 |
| | 19.53125 | 156.25 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 0 |
| Fiber Channel 1 | 25 | 53.125 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 1 |
| | 25 | 106.25 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 |
| Fiber Channel 2 | 16.6015625 | 132.8125 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 0 |
| Infiniband | 25 | 125 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 1 | 0 |
| | 25 | 250 | 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 1 |

POWER SUPPLY FILTERING TECHNIQUES

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The ICS8432I-101 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL. V_{CC} , V_{CCA} , and V_{CCO} should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, power supply isolation is required. Figure 2 illustrates how a 10Ω resistor along with a 10μF and a .01μF bypass capacitor should be connected to each V_{CCA} pin.

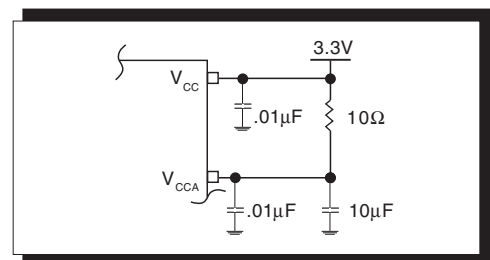


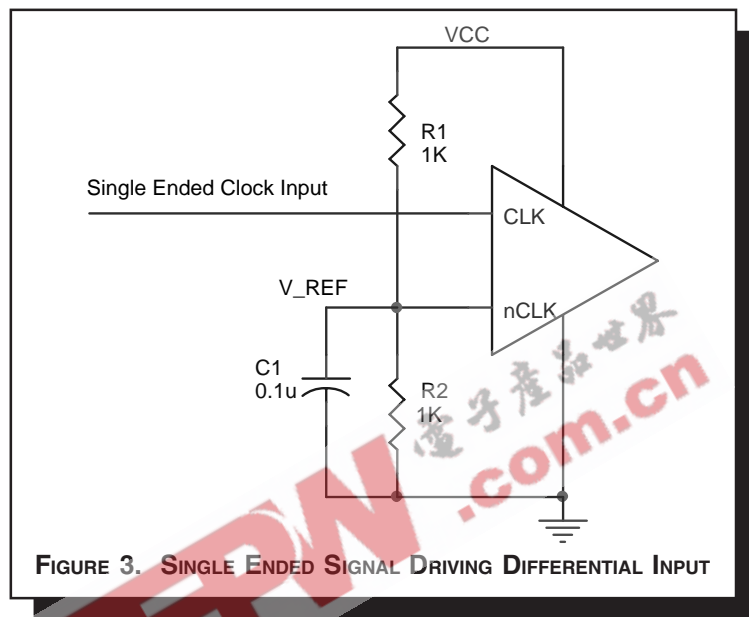
FIGURE 2. POWER SUPPLY FILTERING



WIRING THE DIFFERENTIAL INPUT TO ACCEPT SINGLE ENDED LEVELS

Figure 3 shows how the differential input can be wired to accept single ended levels. The reference voltage $V_{REF} = V_{CC}/2$ is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio

of R1 and R2 might need to be adjusted to position the V_{REF} in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and $V_{CC} = 3.3V$, V_{REF} should be 1.25V and $R2/R1 = 0.609$.



TERMINATION FOR LVPECL OUTPUTS

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

FOUT and nFOUT are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are

designed to drive 50Ω transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion. Figures 4A and 4B show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

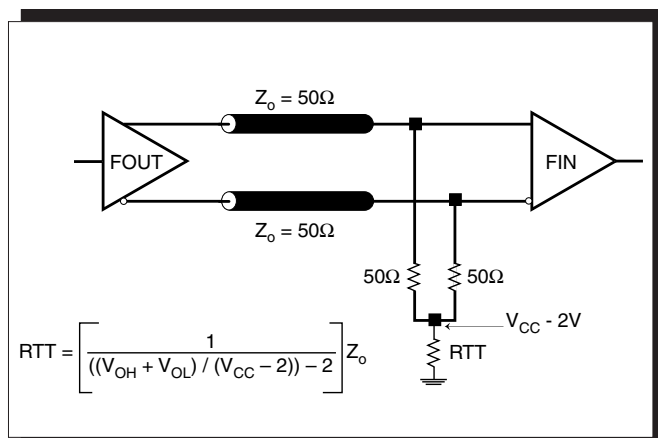


FIGURE 4A. LVPECL OUTPUT TERMINATION

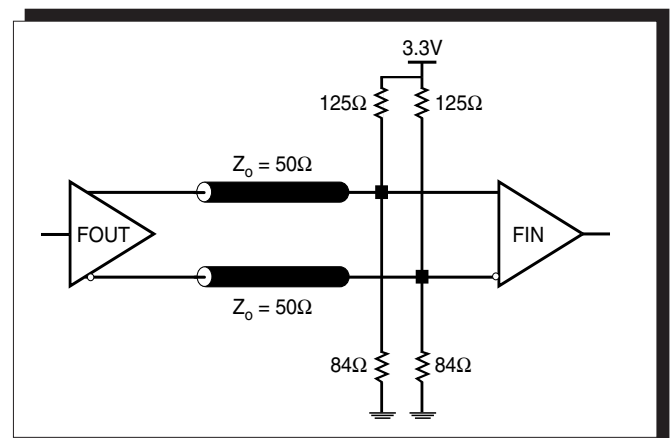


FIGURE 4B. LVPECL OUTPUT TERMINATION



DIFFERENTIAL CLOCK INPUT INTERFACE

The CLK/nCLK accepts LVDS, LVPECL, LVHSTL, SSTL, HCSL and other differential signals. Both V_{SWING} and V_{OH} must meet the V_{PP} and V_{CMR} input requirements. Figures 5A to 5D show interface examples for the HiPerClockS CLK/nCLK input driven by the most common driver types. The input interfaces suggested

here are examples only. Please consult with the vendor of the driver component to confirm the driver termination requirements. For example in *Figure 5A*, the input termination applies for ICS HiPerClockS LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.

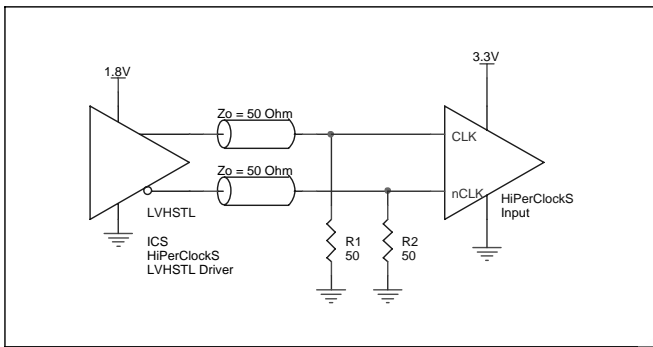


FIGURE 5A. HiPerClockS CLK/nCLK INPUT DRIVEN BY ICS HiPerClockS LVHSTL DRIVER

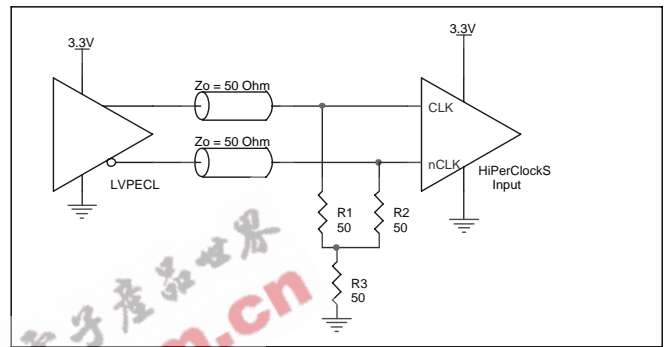


FIGURE 5B. HiPerClockS CLK/nCLK INPUT DRIVEN BY 3.3V LVPECL DRIVER

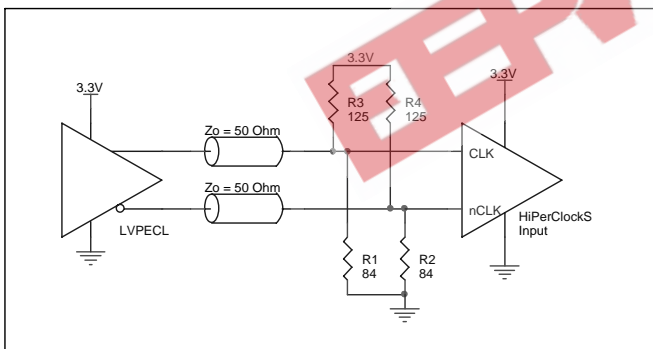


FIGURE 5C. HiPerClockS CLK/nCLK INPUT DRIVEN BY 3.3V LVPECL DRIVER

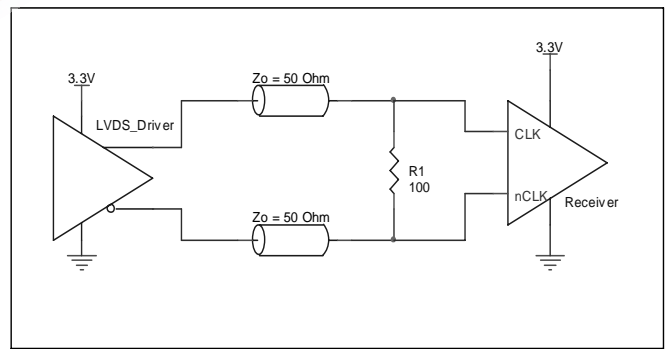


FIGURE 5D. HiPerClockS CLK/nCLK INPUT DRIVEN BY 3.3V LVDS DRIVER



LAYOUT GUIDELINE

The schematic of the ICS8432I-101 layout example used in this layout guideline is shown in *Figure 6A*. The ICS8432I-101 recommended PCB board layout for this example is shown in *Figure 6B*. This layout example is used as a general guideline.

The layout in the actual system will depend on the selected component types, the density of the components, the density of the traces, and the stack up of the P.C. board.

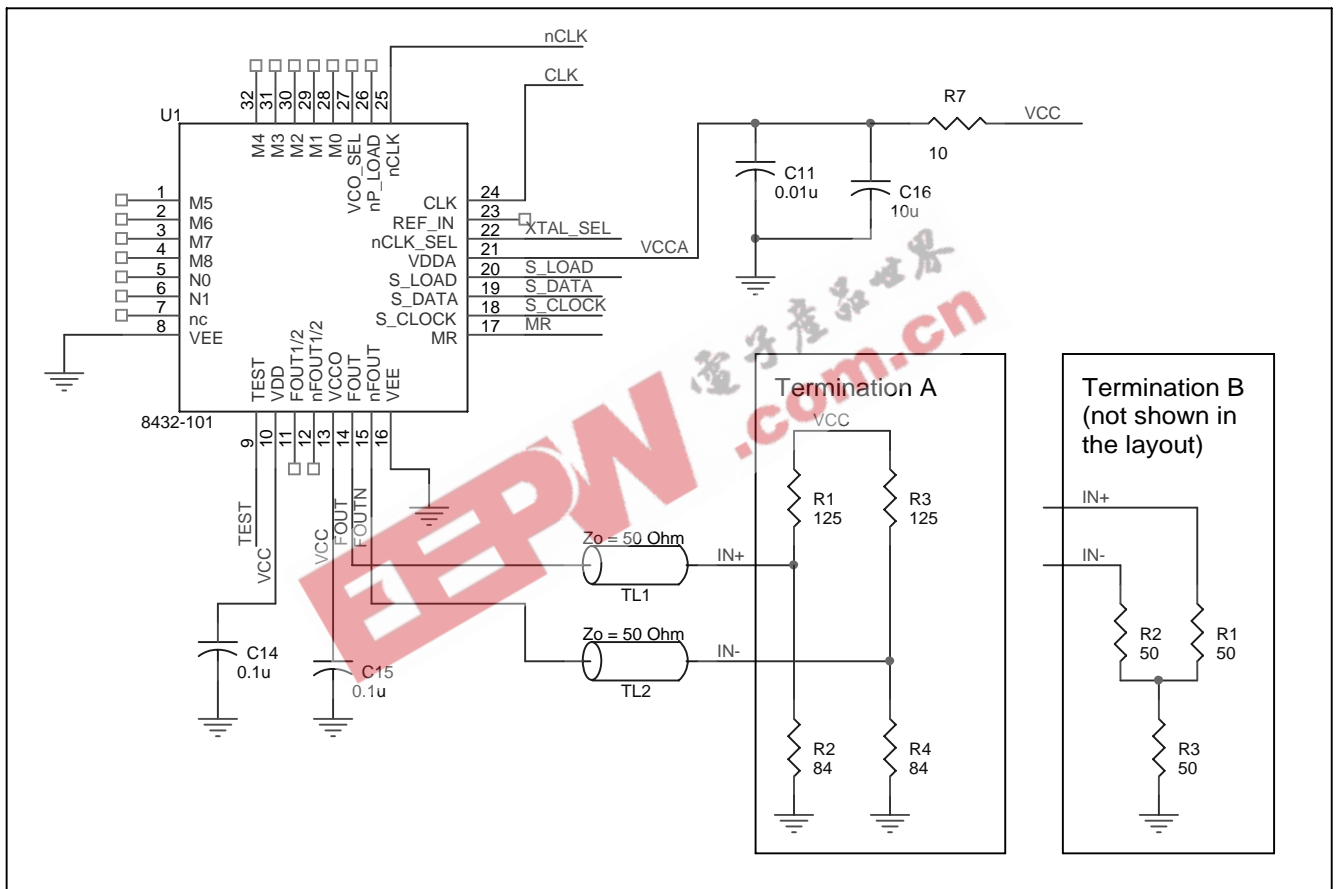


FIGURE 6A. SCHEMATIC OF RECOMMENDED LAYOUT



The following component footprints are used in this layout example: All the resistors and capacitors are size 0603.

POWER AND GROUNDING

Place the decoupling capacitors C14 and C15 as close as possible to the power pins. If space allows, placing the decoupling capacitor at the component side is preferred. This can reduce unwanted inductance between the decoupling capacitor and the power pin generated by the via.

Maximize the pad size of the power (ground) at the decoupling capacitor. Maximize the number of vias between power (ground) and the pads. This can reduce the inductance between the power (ground) plane and the component power (ground) pins.

If V_{CCA} shares the same power supply with V_{CC} , insert the RC filter R7, C11, and C16 in between. Place this RC filter as close to the V_{CCA} as possible.

CLOCK TRACES AND TERMINATION

The component placements, locations and orientations should be arranged to achieve the best clock signal quality. Poor clock signal quality can degrade the system performance or cause system failure. In the synchronous high-speed digital system, the clock signal is less tolerable to poor signal quality than other signals. Any ringing on the rising or falling edge or excessive ring back can cause

system failure. The trace shape and the trace delay might be restricted by the available space on the board and the component location. While routing the traces, the clock signal traces should be routed first and should be locked prior to routing other signal traces.

- The traces with 50Ω transmission lines TL1 and TL2 at FOUT and nFOUT should have equal delay and run adjacent to each other. Avoid sharp angles on the clock trace. Sharp angle turns cause the characteristic impedance to change on the transmission lines.
- Keep the clock trace on same layer. Whenever possible, avoid any vias on the clock traces. Any via on the trace can affect the trace characteristic impedance and hence degrade signal quality.
- To prevent cross talk, avoid routing other signal traces in parallel with the clock traces. If running parallel traces is unavoidable, allow more space between the clock trace and the other signal trace.
- Make sure no other signal trace is routed between the clock trace pair.

The matching termination resistors R1, R2, R3 and R4 should be located as close to the receiver input pins as possible. Other termination schemes can also be used but are not shown in this example.

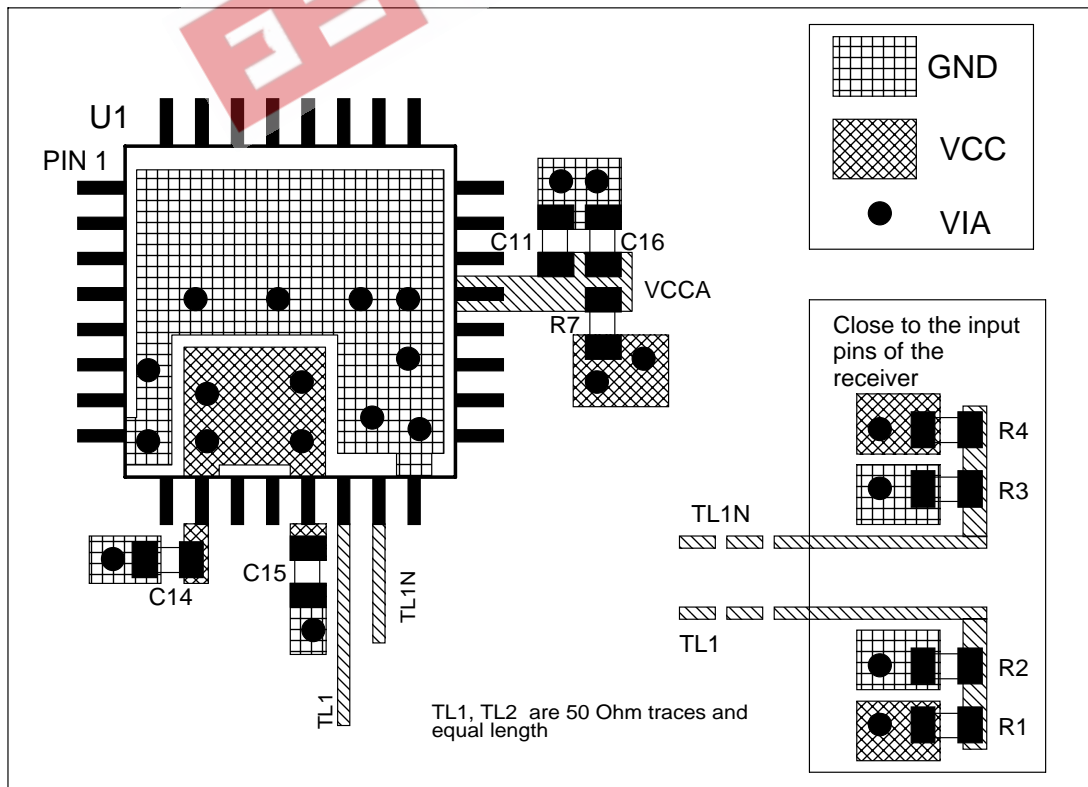


FIGURE 6B. PCB BOARD LAYOUT FOR ICS8432I-101



POWER CONSIDERATIONS

This section provides information on power dissipation and junction temperature for the ICS8432I-101. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS8432I-101 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for $V_{CC} = 3.3V + 5\% = 3.465V$, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)_{MAX} = $V_{CC_MAX} * I_{EE_MAX} = 3.465V * 120mA = 416mW$
- Power (outputs)_{MAX} = **30mW/Loaded Output pair**
If all outputs are loaded, the total power is $2 * 30mW = 60mW$

$$\text{Total Power}_{_MAX} (3.465V, \text{ with all outputs switching}) = 416mW + 60mW = 476mW$$

2. Junction Temperature.

Junction temperature, T_j , is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for HiPerClock^{STM} devices is 125°C.

The equation for T_j is as follows: $T_j = \theta_{JA} * Pd_total + T_A$

T_j = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming a moderate air flow of 200 linear feet per minute and a multi-layer board, the appropriate value is 42.1°C/W per Table 9 below.

Therefore, T_j for an ambient temperature of 85°C with all outputs switching is:

$$85^\circ C + 0.476W * 42.1^\circ C/W = 105^\circ C. \text{ This is well below the limit of } 125^\circ C.$$

This calculation is only an example. T_j will obviously vary depending on the number of loaded outputs, supply voltage, air flow, and the type of board (single layer or multi-layer).

TABLE 9. THERMAL RESISTANCE θ_{JA} FOR 32-PIN LQFP, FORCED CONVECTION

| θ_{JA} by Velocity (Linear Feet per Minute) | | | |
|--|----------|----------|----------|
| | 0 | 200 | 500 |
| Single-Layer PCB, JEDEC Standard Test Boards | 67.8°C/W | 55.9°C/W | 50.1°C/W |
| Multi-Layer PCB, JEDEC Standard Test Boards | 47.9°C/W | 42.1°C/W | 39.4°C/W |

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.



3. Calculations and Equations.

The purpose of this section is to derive the power dissipated into the load.

LVPECL output driver circuit and termination are shown in Figure 7.

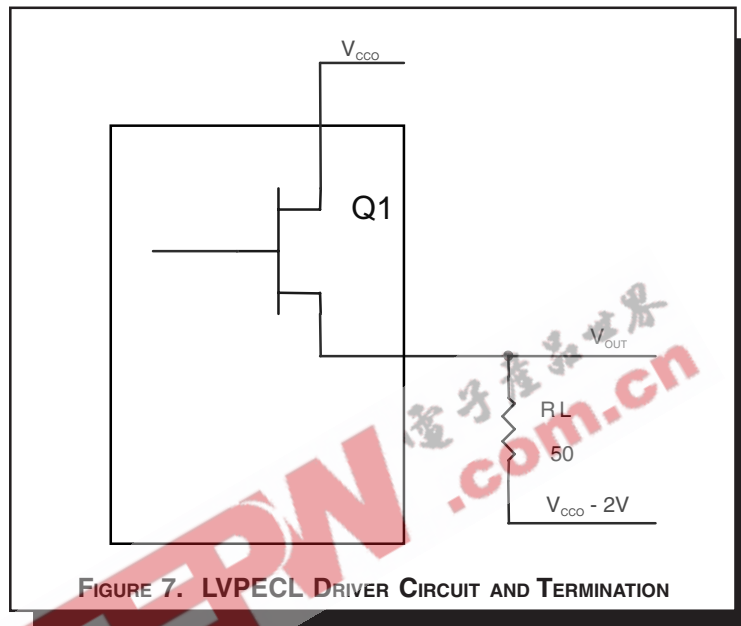


FIGURE 7. LVPECL DRIVER CIRCUIT AND TERMINATION

To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of $V_{CCO} - 2V$.

- For logic high, $V_{OUT} = V_{OH_MAX} = V_{CCO_MAX} - 0.9V$

$$(V_{CCO_MAX} - V_{OH_MAX}) = 0.9V$$

- For logic low, $V_{OUT} = V_{OL_MAX} = V_{CCO_MAX} - 1.7V$

$$(V_{CCO_MAX} - V_{OL_MAX}) = 1.7V$$

Pd_H is power dissipation when the output drives high.
 Pd_L is the power dissipation when the output drives low.

$$Pd_H = [(V_{OH_MAX} - (V_{CCO_MAX} - 2V))/R_L] * (V_{CCO_MAX} - V_{OH_MAX}) = [(2V - (V_{CCO_MAX} - V_{OH_MAX}))/R_L] * (V_{CCO_MAX} - V_{OH_MAX}) = [(2V - 0.9V)/50\Omega] * 0.9V = 19.8mW$$

$$Pd_L = [(V_{OL_MAX} - (V_{CCO_MAX} - 2V))/R_L] * (V_{CCO_MAX} - V_{OL_MAX}) = [(2V - (V_{CCO_MAX} - V_{OL_MAX}))/R_L] * (V_{CCO_MAX} - V_{OL_MAX}) = [(2V - 1.7V)/50\Omega] * 1.7V = 10.2mW$$

Total Power Dissipation per output pair = $Pd_H + Pd_L = 30mW$



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RELIABILITY INFORMATION

TABLE 10. θ_{JA} VS. AIR FLOW TABLE FOR 32 LEAD LQFP

| θ_{JA} by Velocity (Linear Feet per Minute) | | | |
|--|----------|----------|----------|
| | 0 | 200 | 500 |
| Single-Layer PCB, JEDEC Standard Test Boards | 67.8°C/W | 55.9°C/W | 50.1°C/W |
| Multi-Layer PCB, JEDEC Standard Test Boards | 47.9°C/W | 42.1°C/W | 39.4°C/W |

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

TRANSISTOR COUNT

The transistor count for ICS8432I-101 is: 3712



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PACKAGE OUTLINE - Y SUFFIX FOR 32 LEAD LQFP

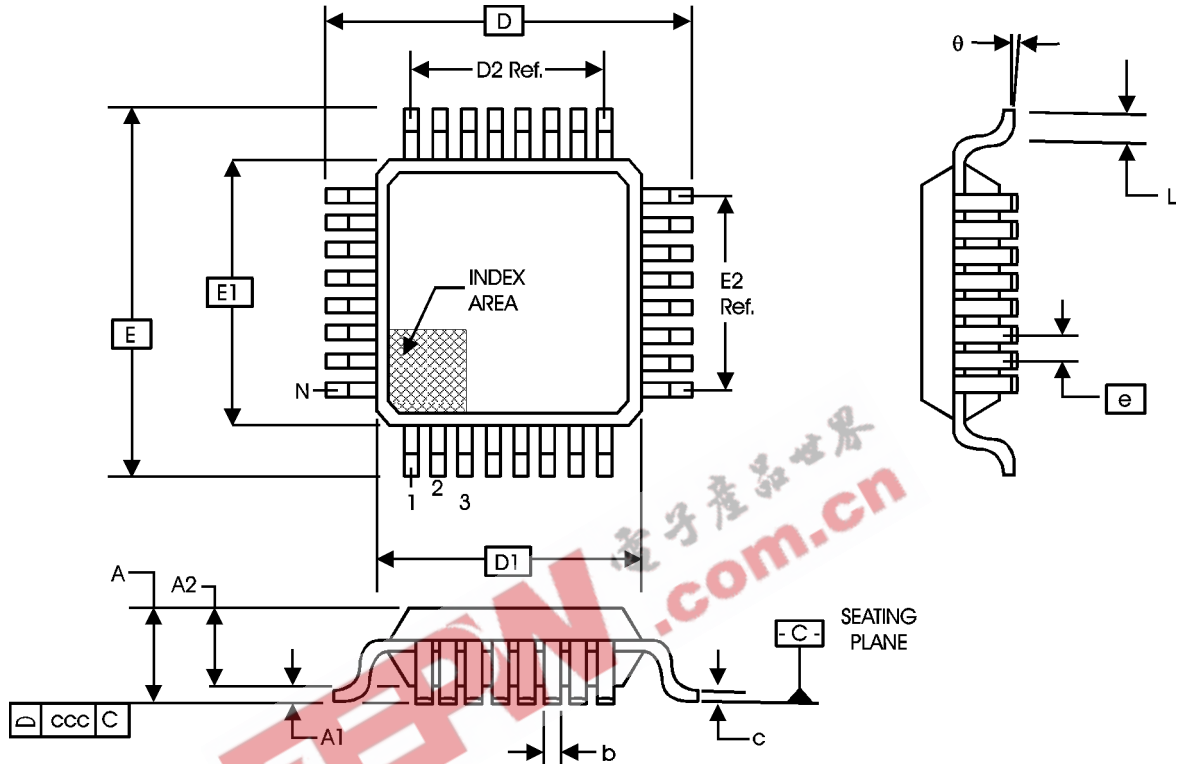
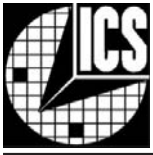


TABLE 11. PACKAGE DIMENSIONS

| SYMBOL | JEDEC VARIATION ALL DIMENSIONS IN MILLIMETERS | | |
|----------|--|------------|---------|
| | BBA | | |
| | MINIMUM | NOMINAL | MAXIMUM |
| N | 32 | | |
| A | | | 1.60 |
| A1 | 0.05 | | 0.15 |
| A2 | 1.35 | 1.40 | 1.45 |
| b | 0.30 | 0.37 | 0.45 |
| c | 0.09 | | 0.20 |
| D | | 9.00 BASIC | |
| D1 | | 7.00 BASIC | |
| D2 | | 5.60 | |
| E | | 9.00 BASIC | |
| E1 | | 7.00 BASIC | |
| E2 | | 5.60 | |
| e | | 0.80 BASIC | |
| L | 0.45 | 0.60 | 0.75 |
| θ | 0° | | 7° |
| ccc | | | 0.10 |

Reference Document: JEDEC Publication 95, MS-026



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TABLE 12. ORDERING INFORMATION

| Part/Order Number | Marking | Package | Shipping Packaging | Temperature |
|-------------------|---------------|--------------------------|--------------------|---------------|
| ICS8432DYI-101 | ICS8432DI-101 | 32 Lead LQFP | 250 | -40°C to 85°C |
| ICS8432DYI-101T | ICS8432DI-101 | 32 Lead LQFP | 1000 tape & reel | -40°C to 85°C |
| ICS8432DYI-101LF | ICS432DI101L | 32 Lead "Lead-Free" LQFP | 250 | -40°C to 85°C |
| ICS8432DYI-101LFT | ICS432DI101L | 32 Lead "Lead-Free" LQFP | 1000 tape & reel | -40°C to 85°C |

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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REVISION HISTORY SHEET

| Rev | Table | Page | Description of Change | Date |
|-----|-------|---------|---|---------|
| A | T12 | 1 17 | Features Section - added Lead-Free bullet. Ordering Information Table - add Lead-Free parts. | 5/23/05 |
| | | | | |
| | | | | |

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